

May 2015

QSE113 / QSE114 Plastic Silicon Infrared Phototransistor

Features

- · NPN Silicon Phototransistor
- · Package Type: Sidelooker
- Medium Wide Reception Angle, 50°
- · Package Material and Color: Black Epoxy

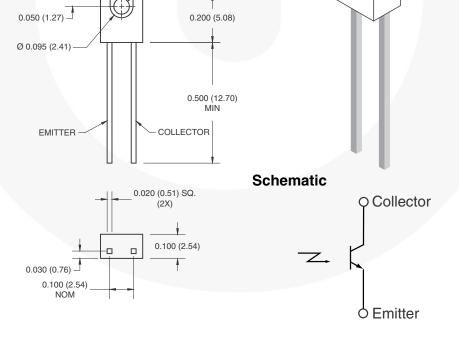
0.087 (2.22)

- · Matched Emitter: QEE113
- · Daylight Filter
- · High Sensitivity
- · Blue dot marking on the top side

Description

The QSE113/114 is a silicon phototransistor encapsulated in a wide angle, infrared transparent, black plastic sidelooker package.

Package Dimensions(1, 2)



1

0.175 (4.44)

Ø 0.065 (1.65)

Notes:

- 1. Dimensions for all drawings are in inches (mm).
- 2. Tolerance of ±0.010 (0.25) on all non-nominal dimensions unless otherwise specified.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
T _{OPR}	Operating Temperature	-40 to +100	°C
T _{STG}	Storage Temperature	-40 to +100	°C
T _{SOL-I}	Soldering Temperature (Iron) ^(4, 5, 6)	240 for 5 sec	°C
T _{SOL-F}	Soldering Temperature (Flow) ^(4, 5)	260 for 10 sec	°C
V _{CE}	Collector Emitter Voltage	30	V
V _{EC}	Emitter Collector Voltage	5	V
P_{D}	Power Dissipation ⁽³⁾	100	mW

Notes:

- 3. Derate power dissipation linearly 1.33 mW/°C above 25°C.
- 4. RMA flux is recommended.
- 5. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 6. Soldering iron 1/16" (1.6mm) minimum from housing.

Electrical / Optical Characteristics

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
λ _{PS}	Peak Sensitivity			880		nm
Θ	Reception Angle			±25		0
I _{CEO}	Collector Emitter Dark Current	$V_{CE} = 10 \text{ V}, E_e = 0$			100	nA
BV _{CEO}	Collector-Emitter Breakdown	I _C = 1 mA	30			V
BV _{ECO}	Emitter-Collector Breakdown	I _E = 100 μA	5			V
I _{C(ON)}	On-State Collector Current ⁽⁷⁾ QSE113	$E_{e} = 0.5 \text{ mW/cm}^{2}, V_{CE} = 5 \text{ V}$	0.25		1.50	- mA
	On-State Collector Current ⁽⁷⁾ QSE114		1.00			
V _{CE(SAT)}	Saturation Voltage ⁽⁷⁾	$E_e = 0.5 \text{ mW/cm}^2$, $I_C = 0.1 \text{ mA}$			0.4	V
t _r	Rise Time	$I_C = 1 \text{ mA}, V_{CC} = 5 \text{ V},$		8		μs
t _f	Fall Time	$R_L = 100 \Omega$		8		μs

Note:

7. $\lambda = 880 \text{ nm (AlGaAs)}$

Typical Performance Characteristics

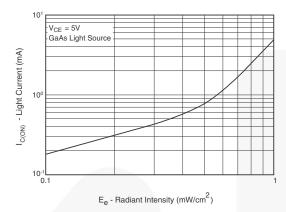
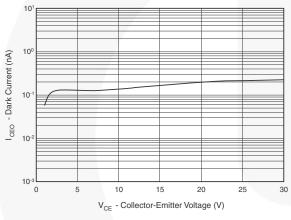


Figure 1. Light Current vs. Radiant Intensity

Figure 2. Angular Response Curve



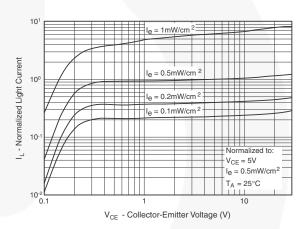


Figure 3. Dark Current vs. Collector - Emitter Voltage Figure 4. Light Current vs. Collector - Emitter Voltage

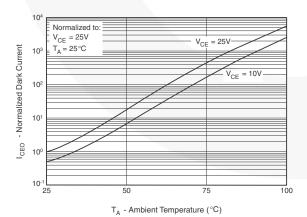


Figure 5. Dark Current vs. Ambient Temperature





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Definition of Terms						
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